



DCR3780V28

Phase Control Thyristor

Replaces DS5813-2 DS5813-3 November 2021 (LN41353)

FEATURES

- Double Side Cooling
- High Surge Capability

APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages VDRM and VRRM (V)	Conditions
DCR3780V28 DCR3780V26 DCR3780V24	2800 2600 2400	$T_{Vj} = -40 ^{\circ} C \text{ to } 125 ^{\circ} C,$ $IDRM = IRRM = 200 mA,$ $VDRM, VRRM t_{P} = 10 ms$ $VDSM \& VRSM =$ $VDRM \& VRRM + 100 V$ $respectively$

Lower voltage grades available.

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DCR3780V28

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

KEY PARAMETERS

\mathbf{V}_{DRM}	2800V
IT(AV)	3760A
Ітѕм	50200A
dV/dt*	1500V/µs
dl/dt	300A/μs

^{*} Higher dV/dt selections are available on request

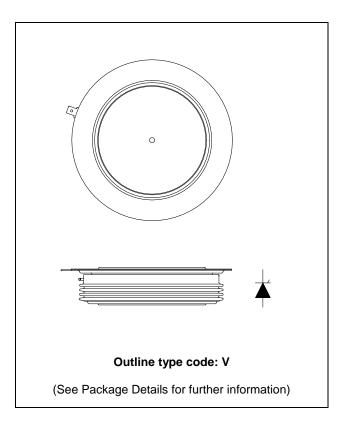


Fig. 1 Package outline

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CURRENT RATINGS

T_{case} = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
Double Si	de Cooled			
İT(AV)	Mean on-state current	Half wave resistive load	3760	А
It(RMS)	RMS value	-	5910	А
lτ	Continuous (direct) on-state current	-	5510	А

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
Ітѕм	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 125°C	50.2	kA
l²t	I2t for fusing	V _R = 0	12.6	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
		Double side cooled	DC	-	7.5	°C/kW
Rth(j-c)		Single side cooled	Anode DC	-	13.0	°C/kW
			Cathode DC	-	17.8	°C/kW
D		Clamping force 54kN (with mounting compound)	Double side	-	2.0	°C/kW
Rth(c-h)	Thermal resistance - case to heatsink		Single side	-	4.0	°C/kW
Tvj	Virtual junction temperature	Blocking VDRM / VRRM		-	125	°C
Tstg	Storage temperature range			-55	125	°C
Fm	Clamping force				59	kN

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DYNAMIC CHARACTERISTICS

Symbol	Parameter	Test Condition	ıs	Min.	Max.	Units
IRRM/IDRM	Peak reverse and off-state current	At VRRM/VDRM, Tcase = 125°C	;	-	200	mA
Vтм	Instantaneous forward voltage	At 4000A peak, Tj = 125°C		1.25	1.40	V
dV/dt	Max. linear rate of rise of off-state voltage	To 67% V _{DRM} , T _j = 125°C, g	ate open	-	1500	V/µs
dl/dt	Rate of rise of on-state current	From 67% V _{DRM} to 2x I _{T(AV)} Gate source 30V, 10Ω	Repetitive 50Hz	-	150	A/µs
di/dt	ivate of fise of off-state current	tr < 0.5µs, Tj = 125°C	Non-repetitive	-	300	A/µs
V	Threshold voltage - Low level	500A to 2700A at Tcase = 125°C		-	0.81	٧
V т(то)	Threshold voltage - High level	2700A to 7000A at Tcase = 125°C		-	0.97	V
_	On-state slope resistance - low level	500A to 2700A at Tcase = 125°C		-	0.17	mΩ
ľτ	On-state slope resistance - High level	2700A to 7000A at Tcase = 125°C		-	0.11	mΩ
tgd	Delay time	$V_D = 67\% \ V_{DRM}, \ gate \ source \ 30V, \ 10\Omega$ $t_T = 0.5 \mu s, \ T_j = 25^{\circ}C$		1	3	μs
tq	Turn-off time	$T_j = 125$ °C, $V_R = 200$ V, $dI/dt = 1$ A/ μ s, $dV_{DR}/dt = 20$ V/ μ s linear		100	250	μs
Qs	Stored charge	Iτ = 2000A, Tj = 125°C, dl/dt = 1A/μs		630	1810	μC
IRR	Reverse recovery current	VR(peak) ~ 1700V, VRM ~ 1100V		21	34	А
lι	Latching current	Tj = 25°C, VD = 5V		-	3	Α
Ін	Holding current	Tj = 25°C, Rg-к = ∞, Iтм = 50	0A, Ιτ = 5A	-	300	mA

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GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
V GT	Gate trigger voltage	VDRM = 5V, Tcase = 25°C	1.5	V
V GD	Gate non-trigger voltage	At 50% VDRM, Tcase = 125°C	0.4	V
Ідт	Gate trigger current	VDRM = 5V, Tcase = 25°C	250	mA
Igp	Gate non-trigger current	At 50% VDRM, Tcase = 125°C	10	mA

CURVES

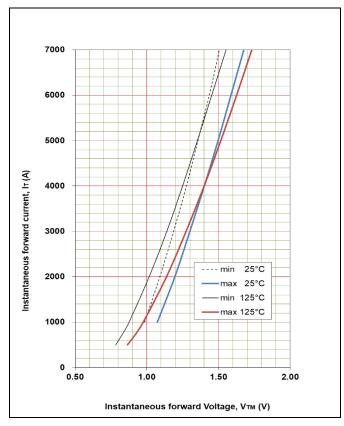


Fig. 2 Maximum & minimum on state characteristics

VTM EQUATION

 $V_{TM} = A + B.ln(I_T) + C.I_T + D.\sqrt{I_T}$

Where A = 0.582097

B = 0.018183

C = 0.000063

D = 0.006577

These values are valid for $T_j = 125^{\circ}C$ for I_{T} 500A to 7000A

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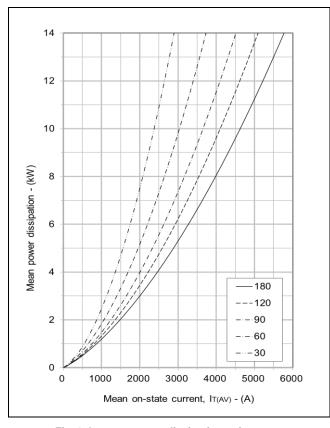


Fig. 3 On-state power dissipation - sine wave

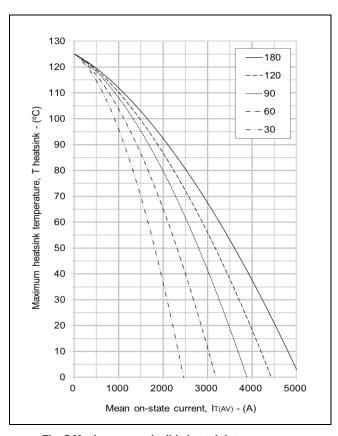


Fig. 5 Maximum permissible heatsink temperature, double side cooled - sine wave

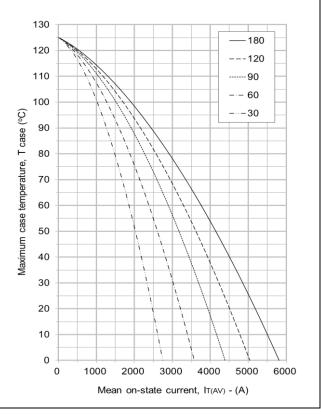


Fig. 4 Maximum permissible case temperature, double side cooled - sine wave

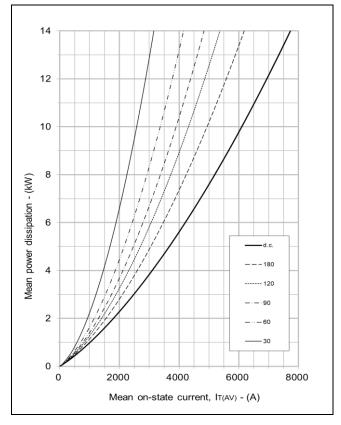


Fig. 6 On-state power dissipation - rectangular wave

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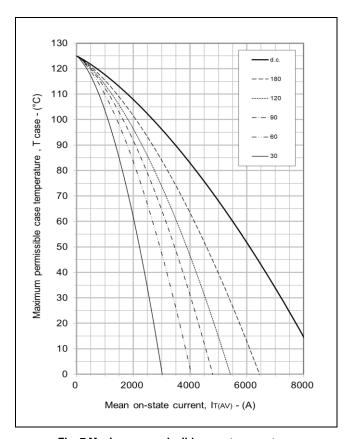
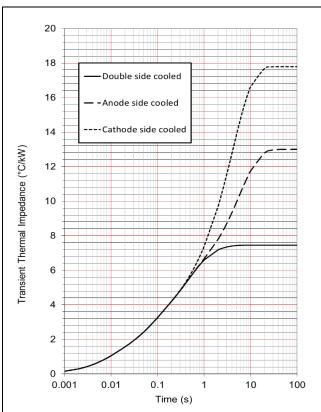


Fig. 7 Maximum permissible case temperature, double side cooled - rectangular wave



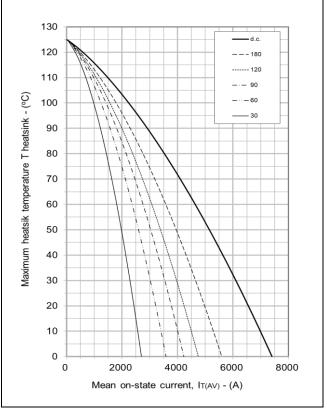


Fig. 8 Maximum permissible heatsink temperature, double side cooled - rectangular wave

		1	2	3	4
Double side	Ri(°C/kW)	0.921	1.830	3.402	1.304
cooled	Ti(s)	0.008	0.058	0.408	1.209
Anode side cooled	Ri(°C/kW)	0.903	1.672	3.010	7.427
	Ti(s)	0.008	0.054	0.314	5.624
Cathode side cooled	Ri(°C/kW)	0.948	2.066	1.688	13.085
	Ti(s)	0.008	0.065	0.389	4.145

$$Z_{th} = \sum_{i=1}^{i=4} R_i \cdot \left(1 - \exp\left(-\frac{T}{T_i}\right)\right)$$

 $\Delta R_{\text{th(j-c)}}$ Conduction

Tables show the increments of thermal resistance R $_{\text{th}(j-s)}$ when the device operates at conduction angles other than d.c.

	Double side co	Double side cooling				
	ΔZ _{th} (_				
θ°	sine.	rect.				
180	1.34	0.88				
120	1.57	1.30				
90	1.83	1.54				
60	2.08	1.81				
30	2.27	2.11				
45	0.00	0.00				

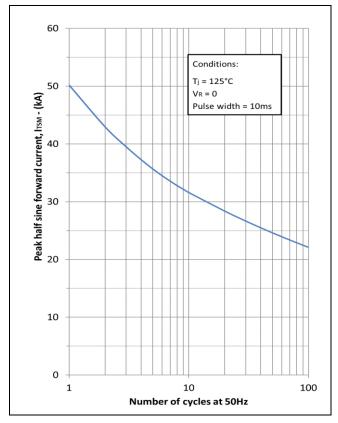
	Anoge Sige	Coolina	
	ΔZ _{th} (z)		
θ°	sine.	rect.	
180	1.34	0.88	
120	1.57	130	
90	1.84	154	
60	2.08	1.81	
30	2.28	2.11	
45	0.27	0.00	

Ca	thode Sideo	thode Sided Cooling		
	ΔZ_t	h (Z)		
θ°	sine.	rect.		
180	1.33	0.88		
120	1.57	1 29		
90	183	1.53		
60	2.07	1.80		
30	2.26	2.10		
15	235	2.26		

Fig. 9 Maximum (limit) transient thermal impedance - junction to case (degC/kW)

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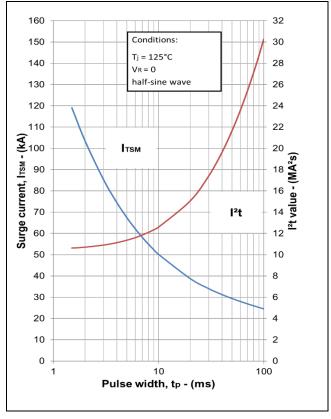


Fig. 10 Multi-cycle surge current

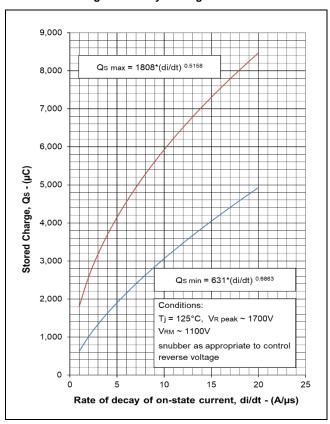


Fig. 12 Stored charge

Fig. 11 Single-cycle surge current

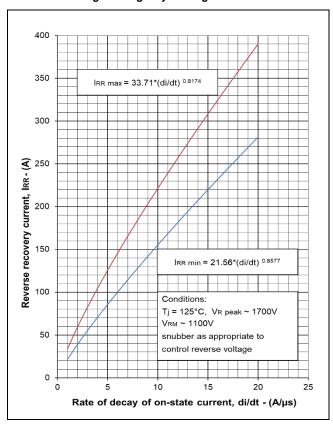


Fig. 13 Reverse recovery current

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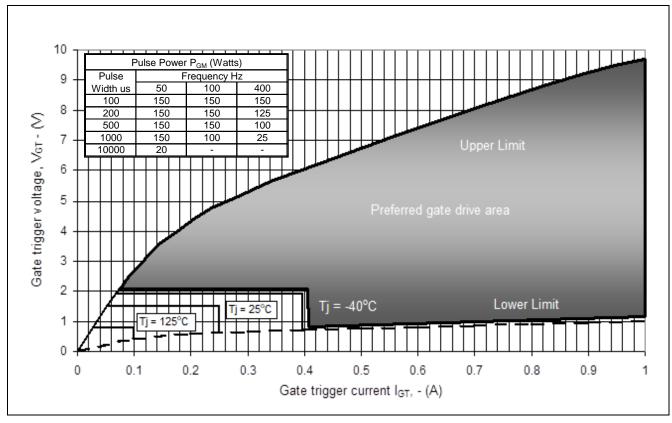


Fig. 14 Gate characteristics

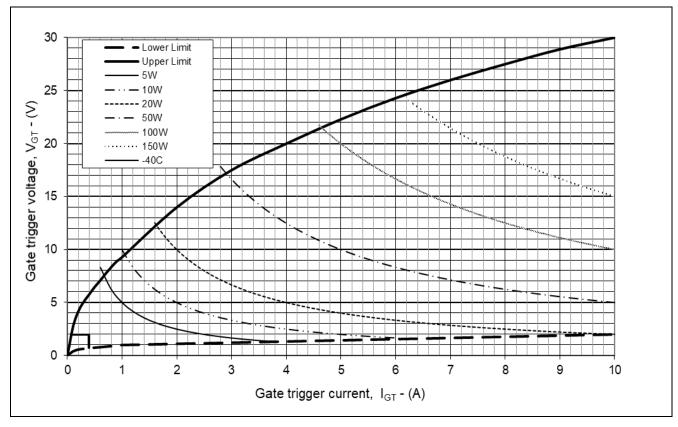


Fig. 15 Gate characteristics

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PACKAGE DETAILS

For further package information, please contact Customer services.

All dimensions in mm, unless stated otherwise.

DO NOT SCALE

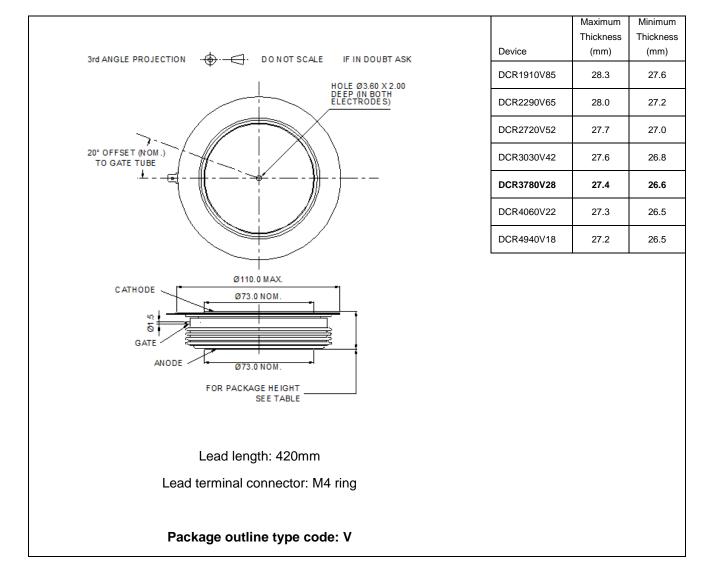


Fig. 16 Package outline

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